NSN 5961-01-327-2854

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-327-2854 **Inclosure Material:** Glass **Overall Length:** Between 0.145 inches and 0.175 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.075 inches **Mounting Method:** Terminal **Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.0 reverse breakdown voltage, dc and 15.0 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 1.50 milliamperes all primaries preset and 5.00 microamperes forward current, average horsepower metric **Power Rating Per Characteristic:** 10.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** Between 1.0 and 2.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: